

Supplementary materials

Phonon dynamics in MoSi₂N₄. Insights from DFT calculations.

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Table S1. Structural data for $\alpha 1$ structure.

Cell length, Å	<i>a</i>	<i>b</i>	<i>c</i>
	2.910606	2.910606	24.989594
Angle, °	alpha	beta	gamma
	90	90	120
Atomic coordinates	x	y	z
Mo1	0.333333	0.666666	0.2
Si1	0	0	0.319903
Si2	0	0	0.080097
N1	0	0	0.149914
N2	0	0	0.250086
N3	0.666667	0.333333	0.059944
N4	0.666666	0.333333	0.340056

Table S2. Structural data for $\alpha 2$ structure.

Cell length, Å	<i>a</i>	<i>b</i>	<i>c</i>
	2.897820	2.897820	25.210600
Angle, °	alpha	beta	gamma
	90	90	120
Atomic coordinates	x	y	z
Mo1	0.333333	0.666666	0.2
Si1	0	0	0.319621
Si2	0	0	0.080379
N1	0	0	0.149994
N2	0	0	0.250006
N3	0.333334	0.666667	0.059738
N4	0.333333	0.666666	0.340262

Table S3. Structural data for $\alpha 3$ structure.

Cell length, Å	<i>a</i>	<i>b</i>	<i>c</i>
	2.912063	2.912063	24.964600
Angle, °	alpha	beta	gamma
	90	90	120
Atomic coordinates	x	y	z
Mo1	0.333333	0.666666	0.199597
Si1	0	0	0.320844
Si2	0	0	0.079292
N1	0	0	0.149197
N2	0	0	0.250526
N3	0.666667	0.333333	0.059060
N4	0.333333	0.666666	0.341484

Table S4. Energy difference of calculated stacking of bulk MoSi₂N₄

Stacking	AB	AC	AA	AB*	AC*
Configuration	$\alpha 1$ structure				
Energy difference relative to AB (eV)	0.0000	-0.0004	0.0877	0.0849	-0.0471
Configuration	$\alpha 2$ structure				
Energy difference relative to AB (eV)	0.0000	0.0004	0.0840	-0.0383	0.0821
Configuration	$\alpha 3$ structure				
Energy difference relative to AB (eV)	0.0000	0.0001	0.0171	-0.0235	-0.0185

Table S5. Structural data for two layered $\alpha 1$ structure.

Cell length, Å	<i>a</i>	<i>b</i>	<i>c</i>
	2.910606	2.910606	40.000000
Angle, °	alpha	beta	gamma
	90	90	120
Atomic coordinates	x	y	z
Mo1	0.33333	0.66667	0.124950
Mo2	0.33333	0.66667	0.374950
Si1	0	0	0.199855
Si2	0	0	0.050040
Si3	0.66667	0.33333	0.449855
Si4	0.66667	0.33333	0.300040
N1	0	0	0.093655
N2	0	0	0.156240
N3	0.66667	0.33333	0.037450
N4	0.66667	0.33333	0.212445
N5	0.66667	0.33333	0.343655
N6	0.66667	0.33333	0.406240
N7	0	0	0.287450
N8	0	0	0.462445

Table S6. Structural data for two layered α_2 structure.

Cell length, Å	<i>a</i>	<i>b</i>	<i>c</i>
	2.89780	2.89780	40.000000
Angle, °	alpha	beta	gamma
	90	90	120
Atomic coordinates	x	y	z
Mo1	0.33333	0.66667	0.126055
Mo2	0	0	0.376055
Si1	0	0	0.201445
Si2	0	0	0.050660
Si3	0.33333	0.66667	0.451445
Si4	0.33333	0.66667	0.300660
N1	0	0	0.094535
N2	0	0	0.157570
N3	0.33333	0.66667	0.037650
N4	0.33333	0.66667	0.214455
N5	0.33333	0.66667	0.344535
N6	0.33333	0.66667	0.407570
N7	0	0	0.287650
N8	0	0	0.464455

Table S7. Structural data for two layered α_3 structure.

Cell length, Å	<i>a</i>	<i>b</i>	<i>c</i>
	2.91210	2.91210	40.000000
Angle, °	alpha	beta	gamma
	90	90	120
Atomic coordinates	x	y	z
Mo1	0.33333	0.66667	0.124570
Mo2	0	0	0.374570
Si1	0	0	0.200245
Si2	0	0	0.049485
Si3	0.33333	0.66667	0.450245
Si4	0.33333	0.66667	0.299490
N1	0	0	0.093115
N2	0	0	0.156355
N3	0.66667	0.33333	0.036860
N4	0.33333	0.66667	0.213125
N5	0.33333	0.66667	0.343115
N6	0.33333	0.66667	0.406355
N7	0.66667	0.33333	0.286860
N8	0	0	0.463125

Table S8. Structural data for bulk $\alpha 1$ structure.

Cell length, Å	<i>a</i>	<i>b</i>	<i>c</i>
	2.910606	2.910606	10.000000
Angle, °	alpha	beta	gamma
	90	90	120
Atomic coordinates	x	y	z
Mo1	0.3333	0.66667	0.2499
Mo2	0.3333	0.66667	0.7499
Si1	0	0	0.39971
Si2	0	0	0.10008
Si3	0.66667	0.33333	0.89971
Si4	0.66667	0.33333	0.60008
N1	0	0	0.18731
N2	0	0	0.31248
N3	0.66667	0.33333	0.07490
N4	0.66667	0.33333	0.42489
N5	0.66667	0.33333	0.68731
N6	0.66667	0.33333	0.81248
N7	0	0	0.57490
N8	0	0	0.92489

Table S9. Structural data for bulk $\alpha 2$ structure.

Cell length, Å	<i>a</i>	<i>b</i>	<i>c</i>
	2.897820	2.897820	10.000000
Angle, °	alpha	beta	gamma
	90	90	120
Atomic coordinates	x	y	z
Mo1	0.33333	0.66667	0.25211
Mo2	0	0	0.75211
Si1	0	0	0.40289
Si2	0	0	0.10132
Si3	0.33333	0.66667	0.90289
Si4	0.33333	0.66667	0.60132
N1	0	0	0.18907
N2	0	0	0.31514
N3	0.33333	0.66667	0.07530
N4	0.33333	0.66667	0.42891
N5	0.33333	0.66667	0.68907
N6	0.33333	0.66667	0.81514
N7	0	0	0.57530
N8	0	0	0.92891

Table S10. Structural data for bulk $\alpha 3$ structure.

Cell length, Å	<i>a</i>	<i>b</i>	<i>c</i>
	2.912063	2.912063	10.000000
Angle, °	alpha	beta	gamma
	90	90	120
Atomic coordinates	x	y	z
Mo1	0.33333	0.66667	0.24914
Mo2	0	0	0.74914
Si1	0	0	0.40049
Si2	0	0	0.09897
Si3	0.33333	0.66667	0.90049
Si4	0.33333	0.66667	0.59898
N1	0	0	0.18623
N2	0	0	0.31271
N3	0.66667	0.33333	0.07372
N4	0.33333	0.66667	0.42625
N5	0.33333	0.66667	0.68623
N6	0.33333	0.66667	0.81271
N7	0.66667	0.33333	0.57372
N8	0	0	0.92625

Table S11. Comparison of wavenumbers (in cm^{-1}) of vibrations in the $\alpha 1$ structure calculated using various DFT approaches.

Expt.	<i>Irreps.</i>	LDA	GGA PBE [S1]	GGA PBE TS [S2]	GGA PBESol [S3]	GGA BLYP [S4]	meta-GGA [S5]
-	E''	126.4	128.9	126.7	126.03	121.5	146.6
-	E'	169.2	167.0	163.3	163.4	168.5	157.7
289	A_1'	285.1	289.9	291.0	285.3	297.51	324.7
348	A_2''	386.3	379.5	383.3	381.6	378.5	406.3
589	E''	568.2	531.9	538.5	547.9	529.3	493.6
634	E'	647.1	612.3	621.2	627.7	600.5	588.3
692	A_1'	703.3	686.1	691.0	679.4	700.2	742.5
	A_2''	704.9	686.5	691.4	681.8	703.0	872.9
-	E''	823.1	801.0	814.4	811.8	780.3	873.1
-	E'	823.4	801.3	814.7	812.1	780.6	873.1
	A_2''	1054.9	1021.5	1033.3	1023.8	1007.5	1046.6
1051	A_1'	1060.4	1029.4	1040.1	1030.5	1018.6	1057.6

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[S2] Tkatchenko, A.; Scheffler, M. Accurate Molecular Van Der Waals Interactions from Ground-State Electron Density and Free-Atom Reference Data. *Phys. Rev. Lett.* 2009, 102 (7), 073005. <https://doi.org/10.1103/PhysRevLett.102.073005>.

[S3] Perdew, J. P.; Ruzsinszky, A.; Csonka, G. I.; Vydrov, O. A.; Scuseria, G. E.; Constantin, L. A.; Zhou, X.; Burke, K. Restoring the Density-Gradient Expansion for Exchange in Solids and Surfaces. *Phys. Rev. Lett.* 2008, 100 (13), 136406. <https://doi.org/10.1103/PhysRevLett.100.136406>.

[S4] Becke, A. D. Density-Functional Exchange-Energy Approximation with Correct Asymptotic Behavior. *Phys. Rev. A* 1988, 38 (6), 3098–3100. <https://doi.org/10.1103/PhysRevA.38.3098>.

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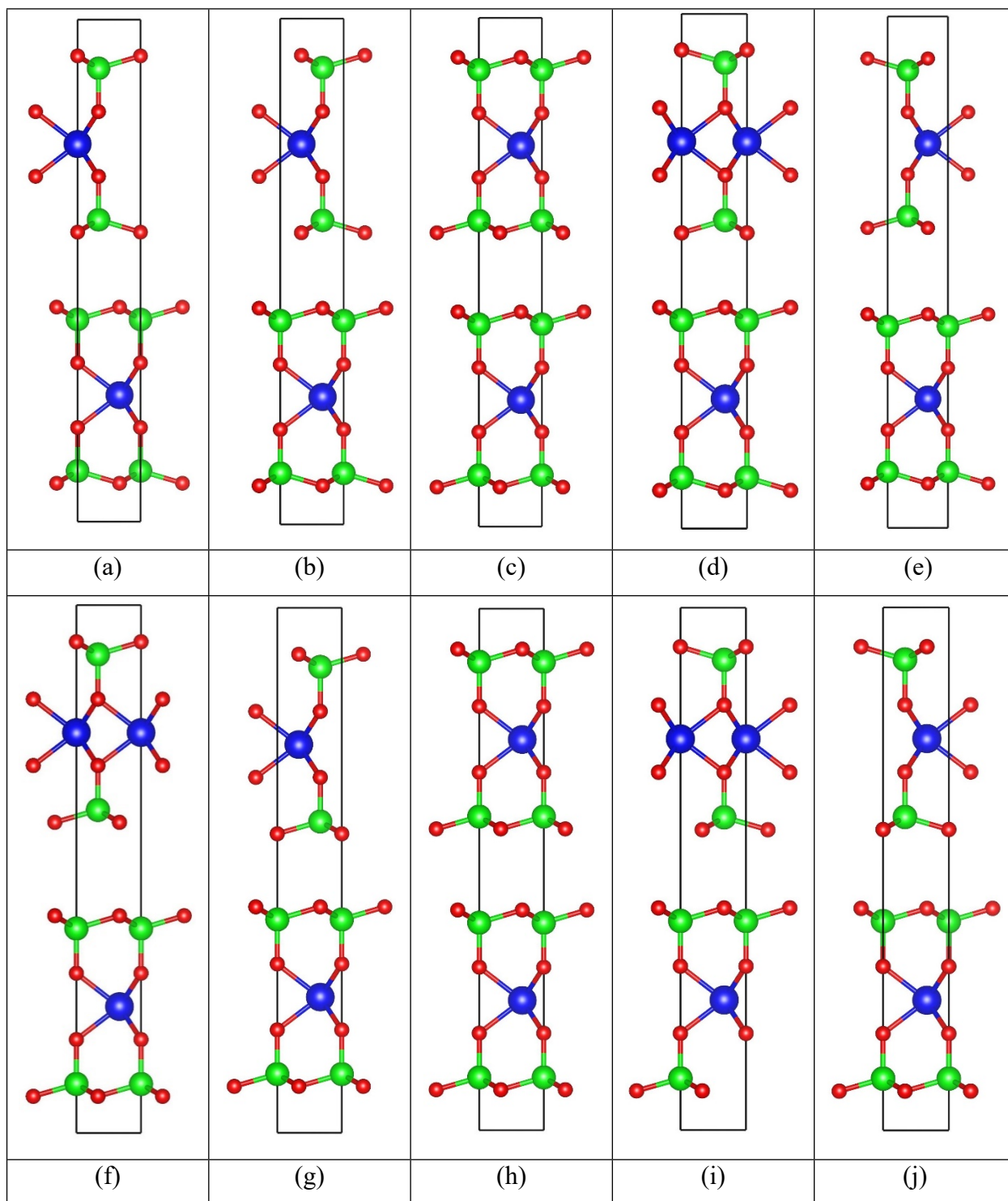


Figure S1. Proposed layer stacking patterns (a) AB, (b) AC, (c) AA, (d) AB*, (e) AC* and (f) AB, (g) AC, (h) AA, (i) AB*, (j) AC* for potentially plausible α_2 and α_3 structures of MoSi_2N_4 , correspondingly.

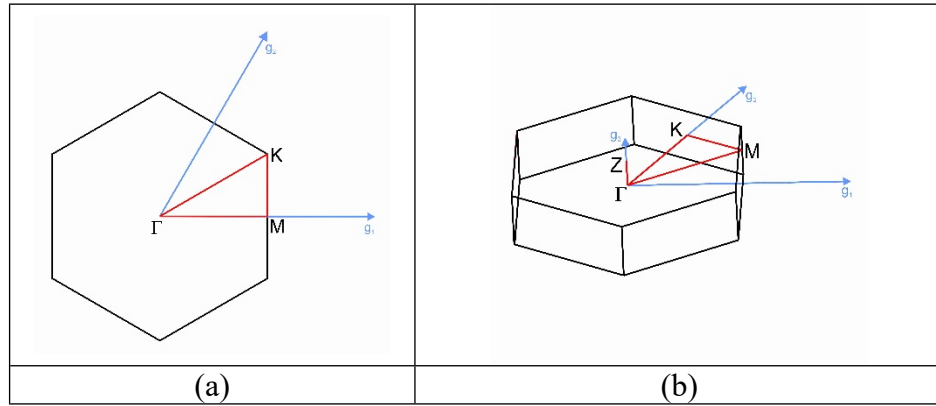


Figure S2. Schemes of Brillouin zone for single layer, double layer (a) and bulk (b) MoSi_2N_4 .

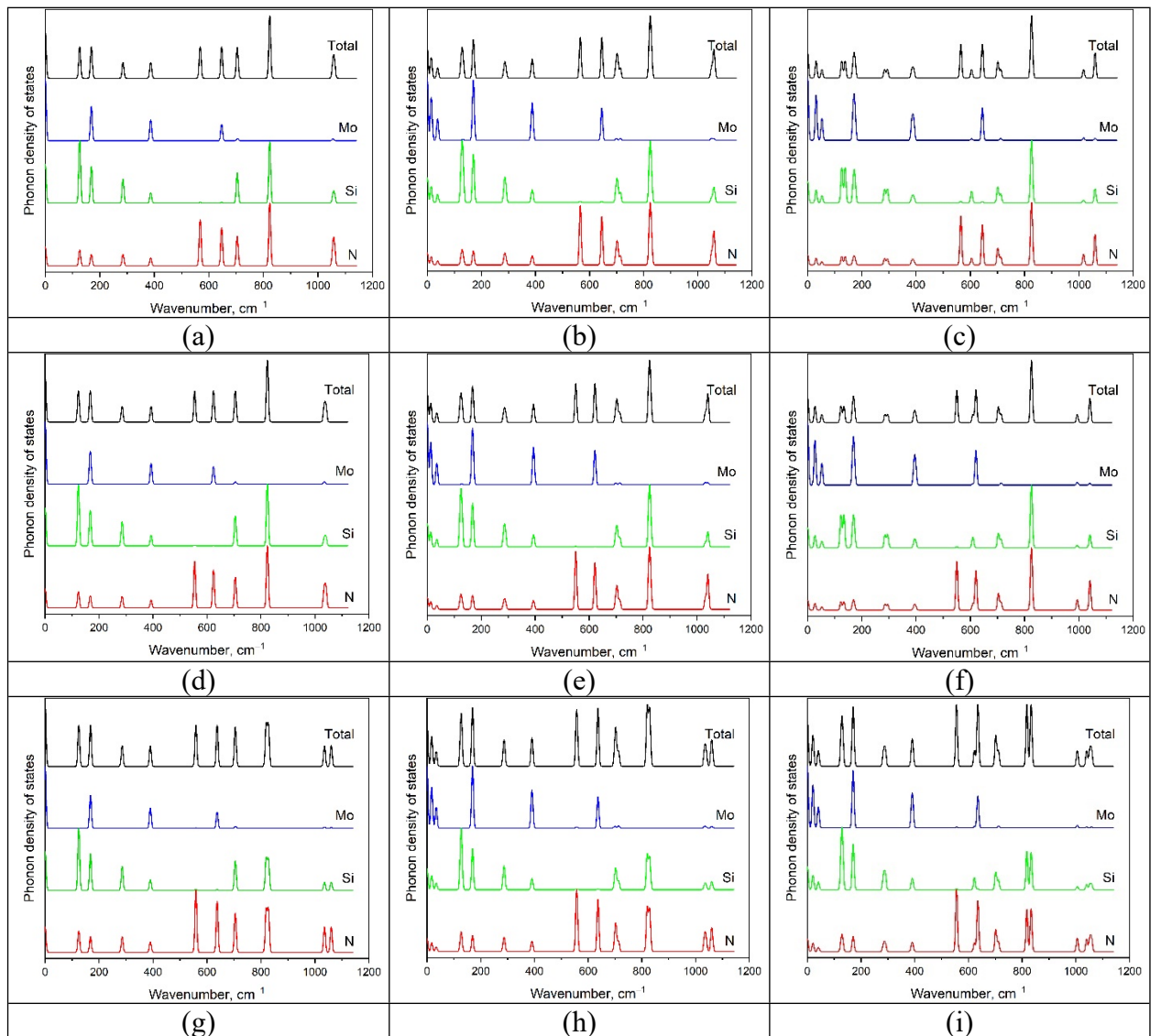


Figure S3. Total and partial phonon density of states for 1 layer, 2 layers and bulk structures of $\alpha 1$ (a, b, c), $\alpha 2$ (d, e, f) and $\alpha 3$ (g, h, i) MoSi_2N_4 configurations.

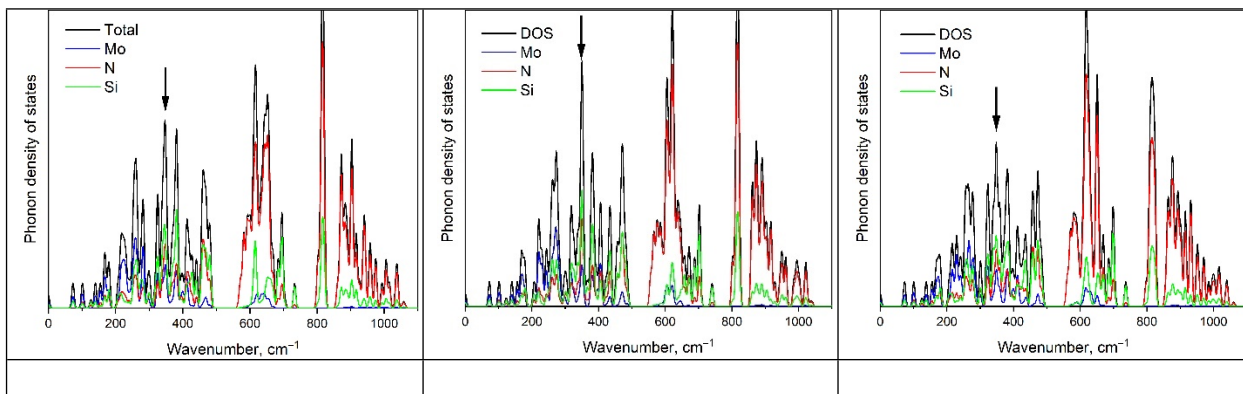


Figure S4. Phonon density of states simulated for $\alpha 1$ (a), $\alpha 2$ (b) and $\alpha 3$ (c) monolayers.